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n re patent application of: Schulze et al.

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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MME	3 Docket No. 1890-0395) Examiner: To be assigned		
Appli	cation No.: 10/587,413) Group Art Unit: To be assigned		
Filed:	July 27, 2006)		
For:	Semiconductor Component Comprising a Temporary Fiel Stopping Area, and Method fo Production Thereof	,		
		I hereby certify that this correspondence is being deposited wi the United States Postal Service first class mail service under: CFR §1.10 on the date indicated below and is addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, and on July 31, 2007		
		(Date of Deposit)		

David R. Moorman

Signature

July 31, 2007

Date of Signature

Name of person mailing Document or Fee

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR $\S1.56$, Applicant hereby discloses the following references, copies of which are enclosed, regarding the above-identified patent application.

Foreign Application	Issue Date	Country
EP 0797 257 A2	24 September 1997	Europe
EP 1 014 453 A1	28 June 2000	Europe
DE 101 00 802 C1	22 August 2002	Germany

10587413 - GAU92826

FORM PTO-1449

MMB DOCKET NO.: 1890-0395 APPLICATION NO.: 10/587,413

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

APPLICANT(S): Schulze et al.

FILING DATE: July 27, 2006 GROUP ART UNIT: To be assigned

SUPPLEMENTA O 1 P E 43 AUG. 0 2 2007

				U.S. PATI	ENT DOCUMENTS			
EXAMINER INITIAL		DOC NUM	UMENT IBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
	AA	US 4	,752,818	21 June 1988	Kushida et al.			
	AB							
	AC							
	AD							
	AE							
	AF							
	AG	i.						
	AH							
	Al							
	AJ							
	AK							
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EXAMINER INITIAL	DOCUMENT NUMBER			DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	Al.	EP 079	7257 A2	24 September 1997	Europe			Yes No
	AM	EP 101	4453 A1	28 June 2000	Europe			Yes No
	AN	DE 101 00 802 C1		22 August 2002	Germany			Yes No
	AO							Yes No
	AP							Yes No
			O.	THER (Including Autho	or, Title, Date, Pertine	ent Pages, etc.)		1
	AQ	1		theide, FJ. et al. "13-k on Power Semiconducto				" 15th Internation
	AR	1						
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	AS	1						

Receipt date: 08/02/2007 Commissioner for Patents

Page 2 of 2

U.S. Patent No. US 4.752.818 Issue Date 21 June 1988 Inventor Kushida et al.

Articles

 Niedernostheide, F.-J. et al. "13-kV Rectifiers: Studies on Diodes and Asymmetric Thyristors." 15th International Symposium on Power Semiconductor Devices & ICs, Cambridge, April 14-17, 2003. Pgs 122-125. (4 pages).

CONCISE EXPLANATION OF FOREIGN LANGUAGE REFERENCES

DE 101 00 802 C1 was cited in a corresponding case. It is believed that DE 101 00 802 C1 may be relevant to claim 47 (as filed in Preliminary Amendment of July 26, 2006. DE 101 00 802 C1 discloses a semiconductor component having embedded p-conductive compensation columns into a n conductive drift region 5, as shown in FIG. 6 of DE 101 00 802 C1.

It is believed that no fees are due for the consideration of this Information

Disclosure Statement. However, the Commissioner is hereby authorized to charge any
deficiency or to credit any overpayment to Deposit Account No. 13-0014, but not to
include any payment of issue fees.

Respectfully Submitted,

July 31, 2007 Maginot, Moore & Beck Chase Tower 111 Monument Circle, Suite 3250 Indianapolis, Indiana 46204-5109 (317) 638-2922

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